

TECHNICAL DATA
DATASHEET 4748, REV. A

SILICON SCHOTTKY RECTIFIER
Ultra Low Reverse Leakage
175°C Operating Temperature

Applications:

- Switching Power Supply
- Converters
- Free-Wheeling Diodes
- Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	45	V
Max. Average Forward Current	$I_{F(AV)}$	Maximum DC Output Current (@ $T_C=100$ °C) (Single, Doubler)	3.0	A
Max. Average Forward Current	$I_{F(AV)}$	Maximum DC Output Current (@ $T_C=100$ °C) (Common Cathode, Common Anode)	6.0	A
Max. Peak One Cycle Non-Repetitive Surge Current	I_{FSM}	8.3 ms, half Sine wave	55	A
Maximun Thermal Resistence (Single)	$R_{\theta JC}$	-	6.35	°C/W
Maximun Thermal Resistence (Common Cathode, Common Anode, Doubler)	$R_{\theta JC}$	-	3.17	°C/W
Max. Junction Temperature	T_J	-	-65 to +175	°C
Max. Storage Temperature	T_{stg}	-	-65 to +175	°C

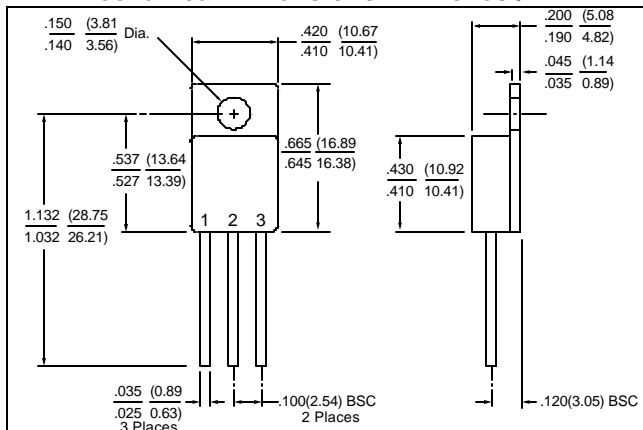
Electrical Characteristics Per Leg:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 3 A, Pulse, $T_J = 25$ °C	0.74	V
	V_{F2}	@ 3 A, Pulse, $T_J = 125$ °C	0.67	V
Max. Reverse Current	I_{R1}	@ $V_R = 45$ V, Pulse, $T_J = 25$ °C	0.08	mA
	I_{R2}	@ $V_R = 45$ V, Pulse, $T_J = 125$ °C	3	mA
Max. Junction Capacitance	C_T	@ $V_R = 5$ V, $T_C = 25$ °C $f_{SIG} = 1$ MHz, $V_{SIG} = 50$ mV (p-p)	160	pF

SENSITRON

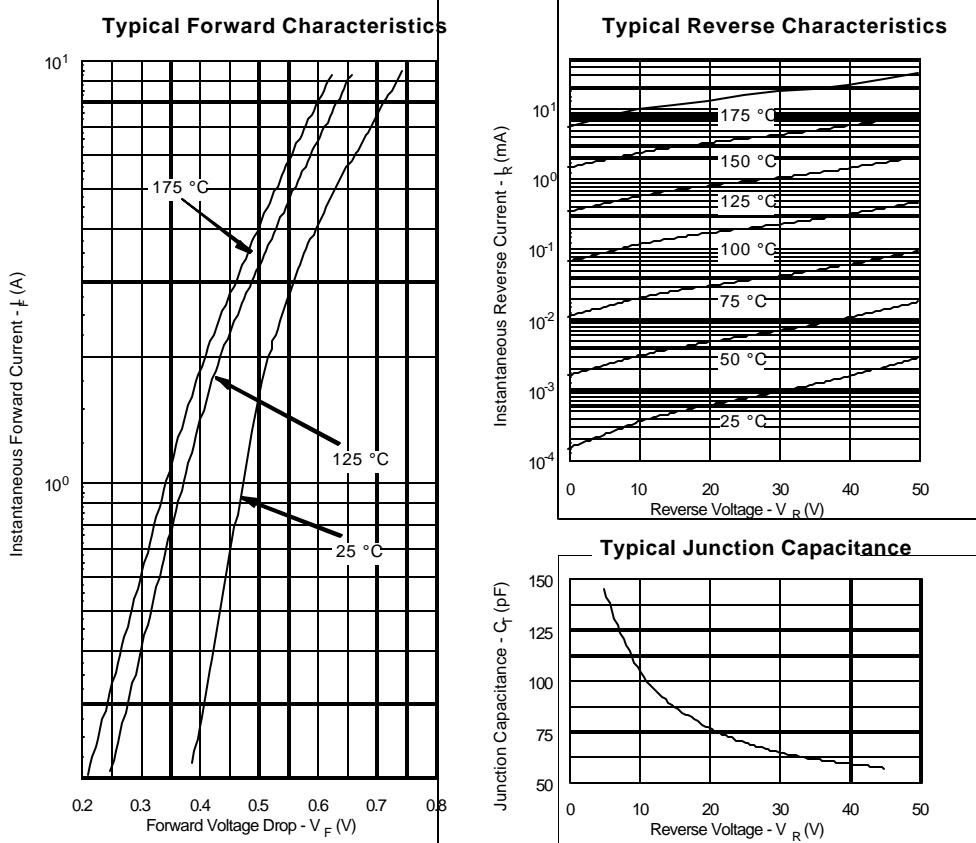
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Mechanical Dimensions: In Inches / mm



TO-257

DEVICE TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DOUBLER (D)	ANODE	CATHODE / ANODE	CATHODE



Note: V_F characteristics are for unpackaged die only.

TECHNICAL DATA

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